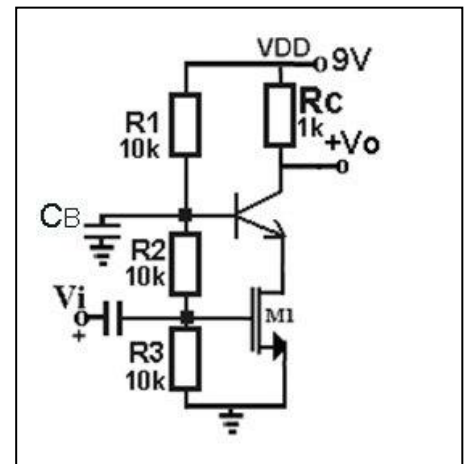


P1 For the MOS transistor in the figure, $\beta = 1\text{mA/V}^2$ and $V_{TH} = 1\text{V}$ are given. For the BJT, $V_{BE} = 0.7\text{V}$ and $\beta_F = 200$ are given. $I_{CQ} = I_{DQ} = 2\text{mA}$. (10P)
Find the ac gain (v_o/v_i) of the circuit. (40P)



P2 All transistors in the figure are the same ($\beta_F = 100$, $|V_{BE}| = 0.6\text{V}$, $V_T = 25\text{mV}$, $V_A = \infty$).

a) DC value for the input (v_i) is 0V . Is the capacitor CE necessary. Explain your answer. (20P)

b) Find ac gain v_o/v_i . (20P)

c) Design I_{KE1} by using transistors (the transistors will have the same parameter values). (20P)

